

20V N-Channel Enhancement-Mode MOSFET

LN2302LT1G

$V_{DS} = 20V$

$R_{DS(ON)}, V_{GS}@4.5V, I_{DS}@2.8A = 60m\Omega$

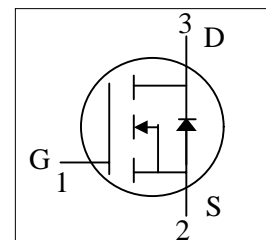
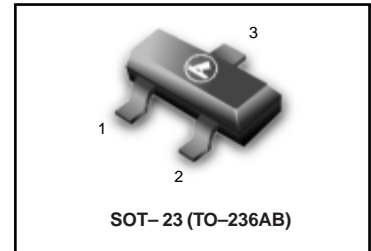
$R_{DS(ON)}, V_{GS}@2.5V, I_{DS}@2.0A = 115m\Omega$

Features

High Density Cell Design For Ultra Low On-Resistance

Improved Shoot-Through FOM

we declare that the material of product compliance with RoHS requirements.



- ▼ High Density Cell Design For Ultra Low On - Resistance
- Improved Shoot-Through FOM

Ordering Information

| Device | Marking | Shipping |
|------------|---------|--------------------|
| LN2302LT1G | N02 | 3000/Tape & Reel |
| LN2302LT3G | N02 | 10,000/Tape & Reel |

Maximum Ratings and Thermal Characteristics ($T_A = 25^\circ C$ unless otherwise noted)

| Parameter | Symbol | Limit | Unit | |
|--|----------------|--------------------|--------------|---|
| Drain-Source Voltage | V_{DS} | 20 | V | |
| Gate-Source Voltage | V_{GS} | ± 8 | | |
| Continuous Drain Current | I_D | 2.3 | A | |
| Pulsed Drain Current ¹⁾ | I_{DM} | 8 | | |
| Maximum Power Dissipation | P_D | $T_A = 25^\circ C$ | 0.9 | W |
| | | $T_A = 75^\circ C$ | 0.57 | |
| Operating Junction and Storage Temperature Range | T_J, T_{stg} | -55 to 150 | $^\circ C$ | |
| Junction-to-Case Thermal Resistance | R_{qJC} | | $^\circ C/W$ | |
| Junction-to-Ambient Thermal Resistance (PCB mounted) ²⁾ | R_{qJA} | 145 | | |

Note: 1. Repetitive Rating: Pulse width limited by the Maximum junction temperature

2. 1-in² 2oz Cu PCB board

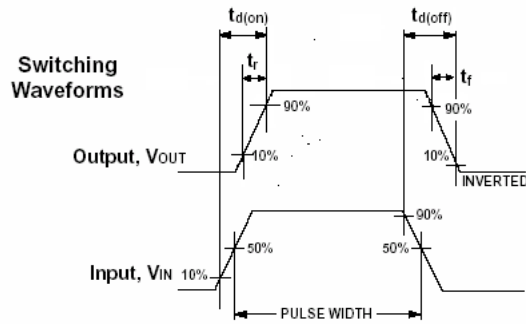
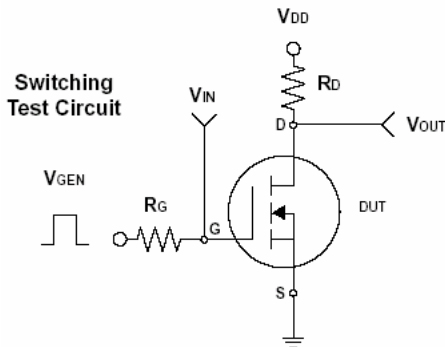
3. Guaranteed by design; not subject to production testing

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ELECTRICAL CHARACTERISTICS

| Parameter | Symbol | Test Condition | Min | Typ | Max | Unit |
|----------------------------------|--------------|---|------|--------|------|------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS} = 0V, I_D = 250\mu A$ | 20 | - | - | V |
| Drain-Source On-State Resistance | $R_{DS(on)}$ | $V_{GS} = 4.5V, I_D = 2.8A$ | | 40 | 60 | mΩ |
| Drain-Source On-State Resistance | $R_{DS(on)}$ | $V_{GS} = 2.5V, I_D = 2.0A$ | | 50 | 115 | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = 250\mu A$ | 0.60 | 0.95 | 1.20 | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 9.6V, V_{GS} = 0V$ | | | -1 | μA |
| Gate Body Leakage | I_{GSS} | $V_{GS} = \pm 8V, V_{DS} = 0V$ | | | ±100 | nA |
| Gate Resistance | R_g | | | | | Ω |
| Forward Transconductance | g_{fs} | $V_{DS} = 5V, I_D = 4.0A$ | | 6.5 | | S |
| Dynamic ³⁾ | | | | | | |
| Total Gate Charge | Q_g | $V_{DS} = 6V, I_D = 2.8A$ $V_{GS} = 4.5V$ | | 3.69 | | nC |
| Gate-Source Charge | Q_{gs} | | | 0.70 | | |
| Gate-Drain Charge | Q_{gd} | | | 1.06 | | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DD} = 6V, R_L = 6\Omega$ $I_D = 1A, V_{GEN} = 4.5V$ $R_G = 6\Omega$ | | 6.16 | | ns |
| Turn-On Rise Time | t_r | | | 7.56 | | |
| Turn-Off Delay Time | $t_{d(off)}$ | | | 16.61 | | |
| Turn-Off Fall Time | t_f | | | 4.07 | | |
| Input Capacitance | C_{iss} | $V_{DS} = 6V, V_{GS} = 0V$ $f = 1.0\text{ MHz}$ | | 427.12 | | pF |
| Output Capacitance | C_{oss} | | | 80.56 | | |
| Reverse Transfer Capacitance | C_{rss} | | | 57.00 | | |
| Source-Drain Diode | | | | | | |
| Max. Diode Forward Current | I_S | | | | 1.6 | A |
| Diode Forward Voltage | V_{SD} | $I_S = -1.6A, V_{GS} = 0V$ | | | 1.2 | V |

Note: Pulse test: pulse width ≤ 300μs, duty cycle ≤ 2%



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TYPICAL ELECTRICAL CHARACTERISTICS

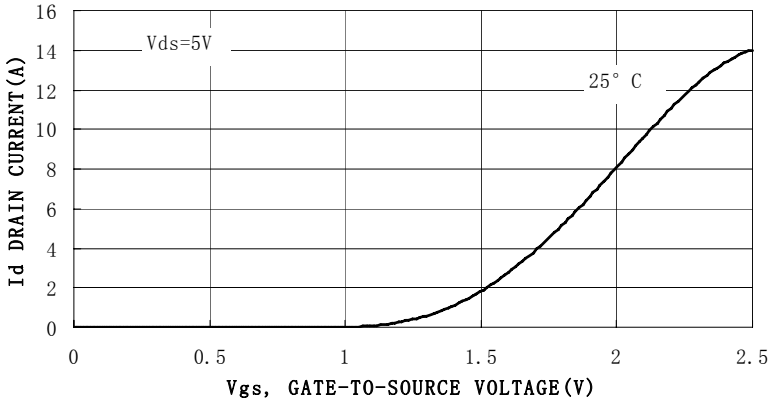


Figure 1. Transfer Characteristics

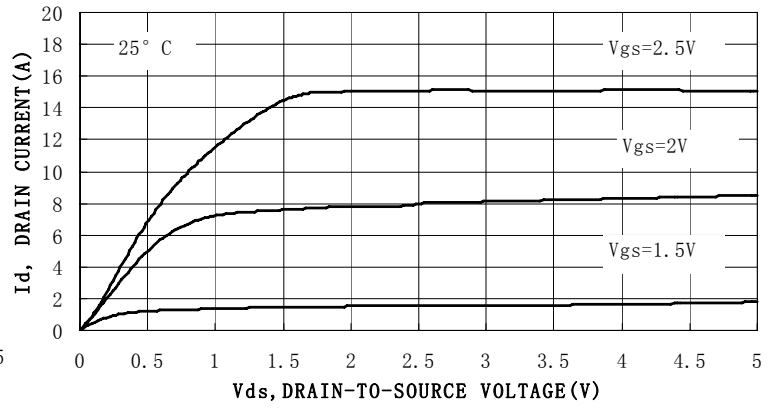


Figure 2. On-Region Characteristics

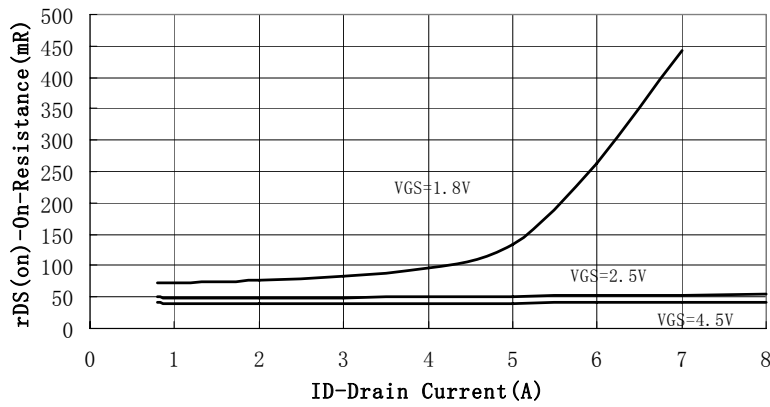


Figure 3. On-Resistance versus Drain Current

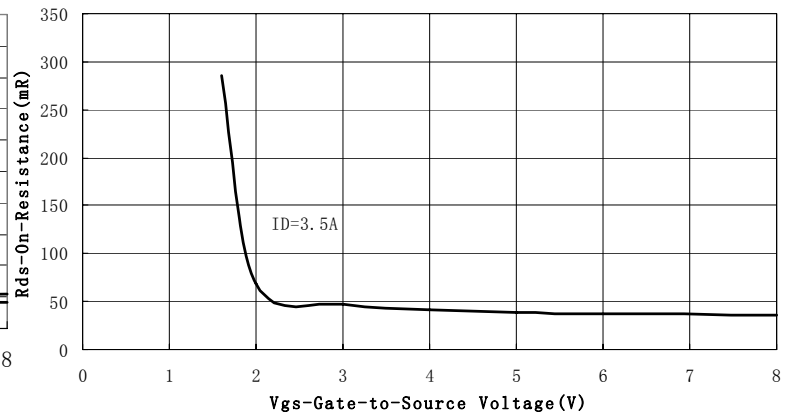


Figure 4. On-Resistance vs. Gate-to-Source Voltage

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TYPICAL ELECTRICAL CHARACTERISTICS

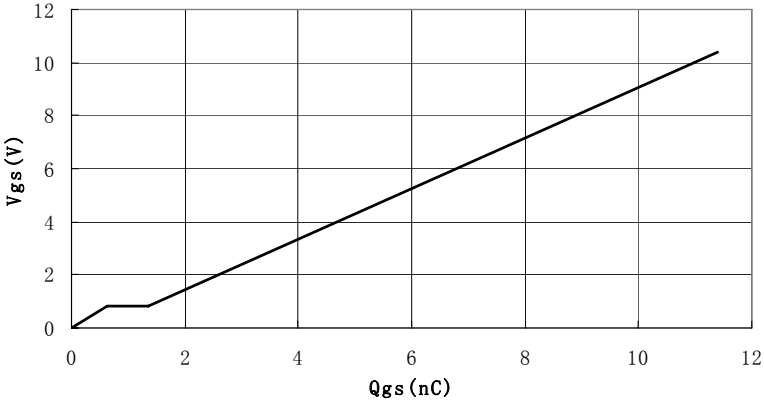


Figure 5. Gate Charge

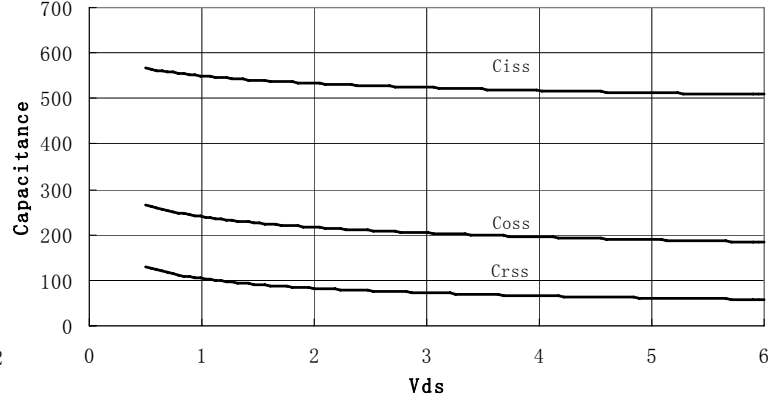


Figure 6. Capacitance

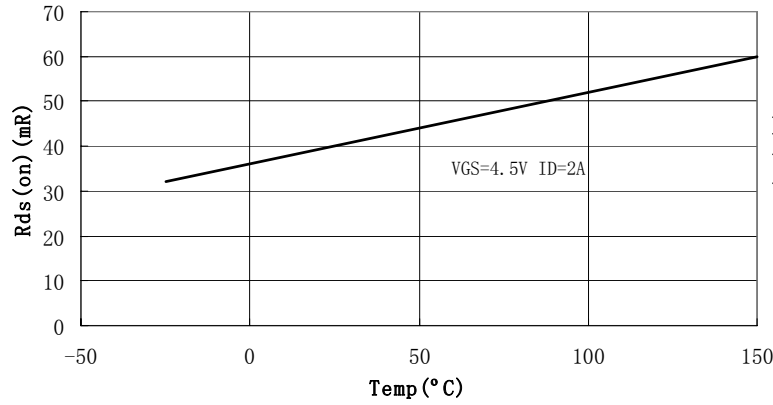


Figure 7. On-Resistance Vs. Junction Temperature

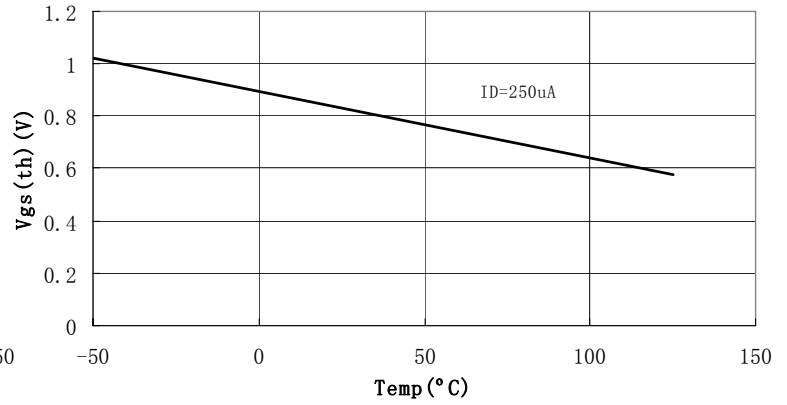


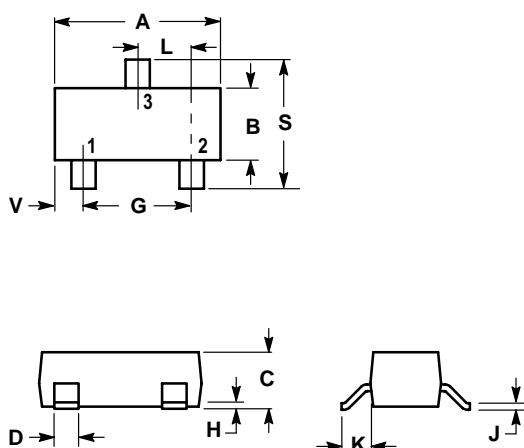
Figure 8. Vth Vs. Junction Temperature

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NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
2. CONTROLLING DIMENSION: INCH.



| DIM | INCHES | | MILLIMETERS | |
|-----|--------|--------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | 0.1102 | 0.1197 | 2.80 | 3.04 |
| B | 0.0472 | 0.0551 | 1.20 | 1.40 |
| C | 0.0350 | 0.0440 | 0.89 | 1.11 |
| D | 0.0150 | 0.0200 | 0.37 | 0.50 |
| G | 0.0701 | 0.0807 | 1.78 | 2.04 |
| H | 0.0005 | 0.0040 | 0.013 | 0.100 |
| J | 0.0034 | 0.0070 | 0.085 | 0.177 |
| K | 0.0140 | 0.0285 | 0.35 | 0.69 |
| L | 0.0350 | 0.0401 | 0.89 | 1.02 |
| S | 0.0830 | 0.1039 | 2.10 | 2.64 |
| V | 0.0177 | 0.0236 | 0.45 | 0.60 |

